



3D PLUS MEMORY MODULE P/N DECODER



	1	2	3	4	5	6	7	8	9	10	11	12	13
3D	<u>XX</u>	<u>000X</u>	<u>00</u>	<u>X</u>	<u>X</u>	<u>0</u>	<u>000</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>00</u>	<u>X</u>



Ex: 3DFN32G08VS8259 IS R00M

1 Module Type

DP : DPRam **MR** : MRam **SS** : μ Solid State Drive (μ SSD)
EE : E²Prom **PO** : PROM **1D** : DDR1
FN : Flash NAND **SF** : StrataFlash **2D** : DDR2
FO : Flash NOR **SD** : Synchronous DRam **3D** : DDR3
FR : FRam **SR** : Static Ram **4D** : DDR4

2 Module Density

nnn K : nnn Kilobit **nnn M** : nnn Megabit **nnn G** : nnn Gigabit
nnn T : nnn Terabit

3 Module Data Bit

04 : x4 Bit **16** : x16 Bit **40** : x40 Bit **64** : x64 Bit **nn** : xnn Bit
08 : x8 Bit **32** : x32 Bit **48** : x48 Bit **72** : x72 Bit

4 Module Voltage

C : 5.0 V **V** : 3.3 V **S** : 2.8 V **T** : 2.5 V **U** : 1.8 V
W : 1.5 V **Y** : 1.35 V **L** : 1.2 V

5 Module Package

B : BGA **L** : LGA **S** : SOP **Q** : QFP **P** : PGA
J : QFJ **C** : Connector **W** : Wire Bond **F** : Flat Pack

6 Stacked Layers

1 : 1 Layer **2** : 2 Layers **4** : 4 Layers **8** : 8 Layers **A** : 10 Layers
n : n Layers

7 Control Features

nnn : Product Flyer Number

Note: The Product Flyer's number characterizes a single product and takes into account the technology flow, the die source and revision, the module's features and the electrical and mechanical user interfaces.

8 Temperature Range

C : 0°C to +70°C
I : -40°C to +85°C
M : -55°C to +125°C
S : Specific

9 Quality Level

N : Commercial Grade
B : Industrial Grade
S : Space Grade

10 Screening Option

: The Space Quality Grade corresponds to the ESA Qualified Quality Grade for Space applications (Category 1 hybrid Manufacturer as per ECSS-Q-ST-60-05C).

P : The Space Quality Grade corresponds to the NASA PEM Selection, Screening and Qualification Flow ref. PEM-INST-002.

Y : The Space Quality Grade corresponds to the Class Y Screening and Qualification Flow.

H : The Industrial Quality Grade corresponds to the Class H Screening and Qualification Flow of the MIL-PRF-38534.

C : Custom screening as per Custom Product Detail Specification.

11 Radiation Assurance

R : Radiation Data Tested
A : Generic Radiation Data Available
- : Not Applicable

12 Speed/Access Time/Firmware Revision

00 : N/A

SRAM

08 : 8ns **10** : 10ns **12** : 12ns
15 : 15ns **20** : 20ns

MRAM

40 : 40ns

FRAM

60 : 60ns

SDRAM

50 : 5ns **60** : 6ns
55 : 5.5ns **70** : 7ns
75 : 7.5ns, PC133 **80** : 8ns

DDR

0 0
5 : 200MHz **C** : CL3
6 : 166MHz **B** : CL2.5
7 : 133MHz **A** : CL2
8 : 100MHz

DDR2

0 0
4 : DDR2-400 (200Mhz) **A** : CL=3
5 : DDR2-533 (266Mhz) **C** : CL=4
6 : DDR2-667 (333Mhz) **E** : CL=5
8 : DDR2-800 (400Mhz) **G** : CL=6
9 : DDR2-1066 (533Mhz) **H** : CL=7

DDR3

0 0
F : DDR3-1066 (533Mhz) **8** : CL=7
H : DDR3-1333 (667Mhz) **9** : CL=9
K : DDR3-1600 (800Mhz) **0** : CL=11
M : DDR3-1866 (933Mhz) **A** : CL=13

FLASH

03 : 30ns **09** : 90ns **13** : 130ns
05 : 50ns **10** : 100ns **35** : 35ns
07 : 70ns **11** : 110ns **25** : 25ns
08 : 80ns **12** : 120ns

μ SSD

nn : Firmware Revision Number

13 Module Option

: No Option*

A : "ARATHANE" Finish

S : "SOLITHANE 113" Finish

L : SnPb termination

M : "MAPSIL" Finish

T : TANTALUM Shielding

G : Gullwing

* By default, there is neither finishing nor shielding.